

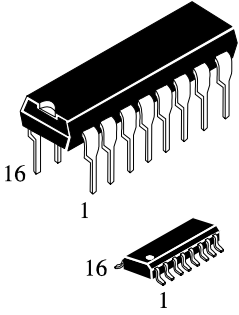
**IN74AC258**

**Quad 2-Input Data Selector/Multiplexer  
with 3-State Outputs  
High-Speed Silicon-Gate CMOS**

The IN74AC258 is identical in pinout to the LS/ALS258, HC/HCT258. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LS/ALS outputs.

This device selects a (4-bit) nibble from either the A or B inputs as determined by the Select input. The nibble is presented at the outputs in inverted from when the Output Enable pin is at a low level. A high level on the Output Enable pin switches the outputs into the high-impedance state.

- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0  $\mu$ A; 0.1  $\mu$ A @ 25°C
- High Noise Immunity Characteristic of CMOS Devices
- Outputs Source/Sink 24 mA

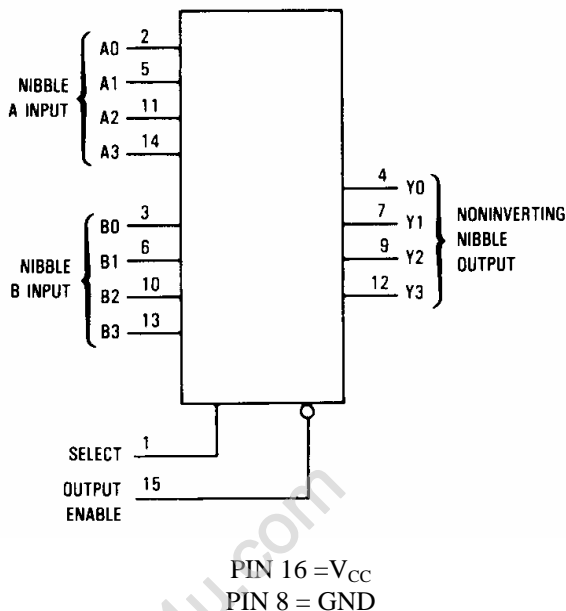


N SUFFIX  
PLASTIC

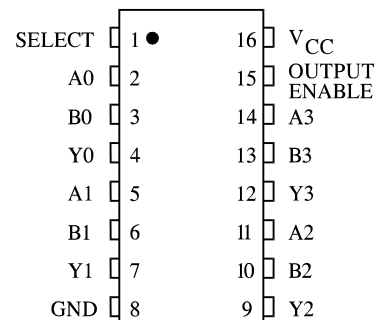
D SUFFIX  
SOIC

**ORDERING INFORMATION**  
IN74AC258N Plastic  
IN74AC258D SOIC  
 $T_A = -40^\circ$  to  $85^\circ$  C for all packages

**LOGIC DIAGRAM**



**PIN ASSIGNMENT**



**FUNCTION TABLE**

Inputs		Outputs Y0-Y3
Output Enable	Select	
H	X	Z
L	L	$\overline{A0-A3}$
L	H	$\overline{B0-B3}$

X=don't care

Z = high-impedance state

A0-A3,B0-B3=the levels of the respective Nibble Inputs

**MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA
I <sub>OUT</sub>	DC Output Sink/Source Current, per Pin	±50	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins	±50	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

\*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	2.0	6.0	V	
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V	
T <sub>J</sub>	Junction Temperature (PDIP)		140	°C	
T <sub>A</sub>	Operating Temperature, All Package Types	-40	+85	°C	
I <sub>OH</sub>	Output Current - High		-24	mA	
I <sub>OL</sub>	Output Current - Low		24	mA	
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time * (except Schmitt Inputs)	V <sub>CC</sub> =3.0 V V <sub>CC</sub> =4.5 V V <sub>CC</sub> =5.5 V	0 0 0	150 40 25	ns/V

\* V<sub>IN</sub> from 30% to 70% V<sub>CC</sub>

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range GND ≤ (V<sub>IN</sub> or V<sub>OUT</sub>) ≤ V<sub>CC</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

**DC ELECTRICAL CHARACTERISTICS** (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limits		Unit	
				25 °C	-40°C to 85°C		
V <sub>IH</sub>	Minimum High-Level Input Voltage	V <sub>OUT</sub> =0.1 V or V <sub>CC</sub> -0.1 V	3.0	2.1	2.1	V	
			4.5	3.15	3.15		
			5.5	3.85	3.85		
V <sub>IL</sub>	Maximum Low - Level Input Voltage	V <sub>OUT</sub> =0.1 V or V <sub>CC</sub> -0.1 V	3.0	0.9	0.9	V	
			4.5	1.35	1.35		
			5.5	1.65	1.65		
V <sub>OH</sub>	Minimum High-Level Output Voltage	I <sub>OUT</sub> ≤ -50 μA	3.0	2.9	2.9	V	
			4.5	4.4	4.4		
			5.5	5.4	5.4		
			*V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> =-12 mA	3.0	2.56		2.46
			I <sub>OH</sub> =-24 mA I <sub>OH</sub> =-24 mA	4.5	3.86		3.76
5.5	4.86	4.76					
V <sub>OL</sub>	Maximum Low-Level Output Voltage	I <sub>OUT</sub> ≤ 50 μA	3.0	0.1	0.1	V	
			4.5	0.1	0.1		
			5.5	0.1	0.1		
			*V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> =12 mA	3.0	0.36		0.44
			I <sub>OL</sub> =24 mA I <sub>OL</sub> =24 mA	4.5	0.36		0.44
5.5	0.36	0.44					
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	5.5	±0.1	±1.0	μA	
I <sub>OZ</sub>	Maximum Three-State Leakage Current	V <sub>IN</sub> (OE)= V <sub>IH</sub> or V <sub>IL</sub> V <sub>IN</sub> =V <sub>CC</sub> or GND V <sub>OUT</sub> =V <sub>CC</sub> or GND	5.5	±0.5	±5.0	μA	
I <sub>OLD</sub>	+Minimum Dynamic Output Current	V <sub>OLD</sub> =1.65 V Max	5.5		75	mA	
I <sub>OHD</sub>	+Minimum Dynamic Output Current	V <sub>OHD</sub> =3.85 V Min	5.5		-75	mA	
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	V <sub>IN</sub> =V <sub>CC</sub> or GND	5.5	8.0	80	μA	

\* All outputs loaded; thresholds on input associated with output under test.

+Maximum test duration 2.0 ms, one output loaded at a time.

Note: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>

**AC ELECTRICAL CHARACTERISTICS** ( $C_L=50\text{pF}$ , Input  $t_r=t_f=3.0\text{ ns}$ )

Symbol	Parameter	$V_{CC}^*$ V	Guaranteed Limits				Unit
			25 °C		-40°C to 85°C		
			Min	Max	Min	Max	
$t_{PLH}$	Propagation Delay, Nibble A or B to Output Y (Figure 1)	3.3 5.0	2.0 1.5	9.5 7.5	1.5 1.0	11.0 8.5	ns
$t_{PHL}$	Propagation Delay, Nibble A or B to Output Y (Figure 1)	3.3 5.0	2.0 1.5	8.5 6.5	1.5 1.0	9.5 7.0	ns
$t_{PLH}$	Propagation Delay, Select to Output Y (Figure 2)	3.3 5.0	3.0 2.0	12.0 9.5	2.5 1.5	14.0 10.5	ns
$t_{PHL}$	Propagation Delay, Select to Output Y (Figure 2)	3.3 5.0	2.5 1.5	11.5 9.0	2.0 1.5	13.0 10.0	ns
$t_{PZH}$	Propagation Delay, Output Enable to Output Y (Figure 3)	3.3 5.0	2.5 1.5	9.5 7.5	2.0 1.5	10.5 8.5	ns
$t_{PZL}$	Propagation Delay, Output Enable to Output Y (Figure 3)	3.3 5.0	2.0 1.5	9.0 7.0	1.5 1.0	10.0 8.0	ns
$t_{PHZ}$	Propagation Delay, Output Enable to Output Y (Figure 3)	3.3 5.0	2.5 2.0	10.0 8.5	2.0 1.5	11.0 9.0	ns
$t_{PLZ}$	Propagation Delay, Output Enable to Output Y (Figure 3)	3.3 5.0	2.0 1.5	9.0 7.0	2.0 1.5	10.0 8.0	ns
$C_{IN}$	Maximum Input Capacitance	5.0	4.5		4.5		pF

$C_{PD}$	Power Dissipation Capacitance	Typical @25°C, $V_{CC}=5.0\text{ V}$		pF
		55		

\*Voltage Range 3.3 V is 3.3 V  $\pm$ 0.3 V

Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V

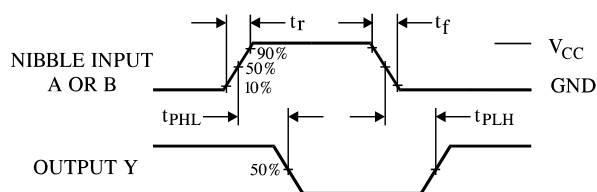


Figure 1. Switching Waveforms

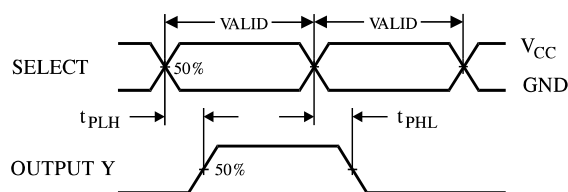


Figure 2. Switching Waveforms

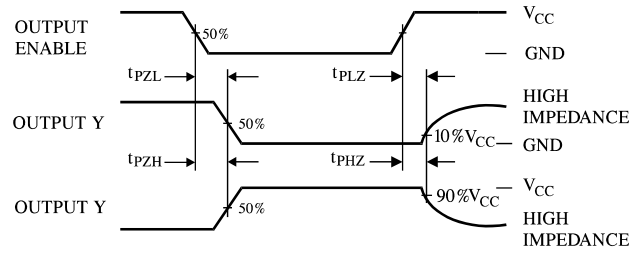
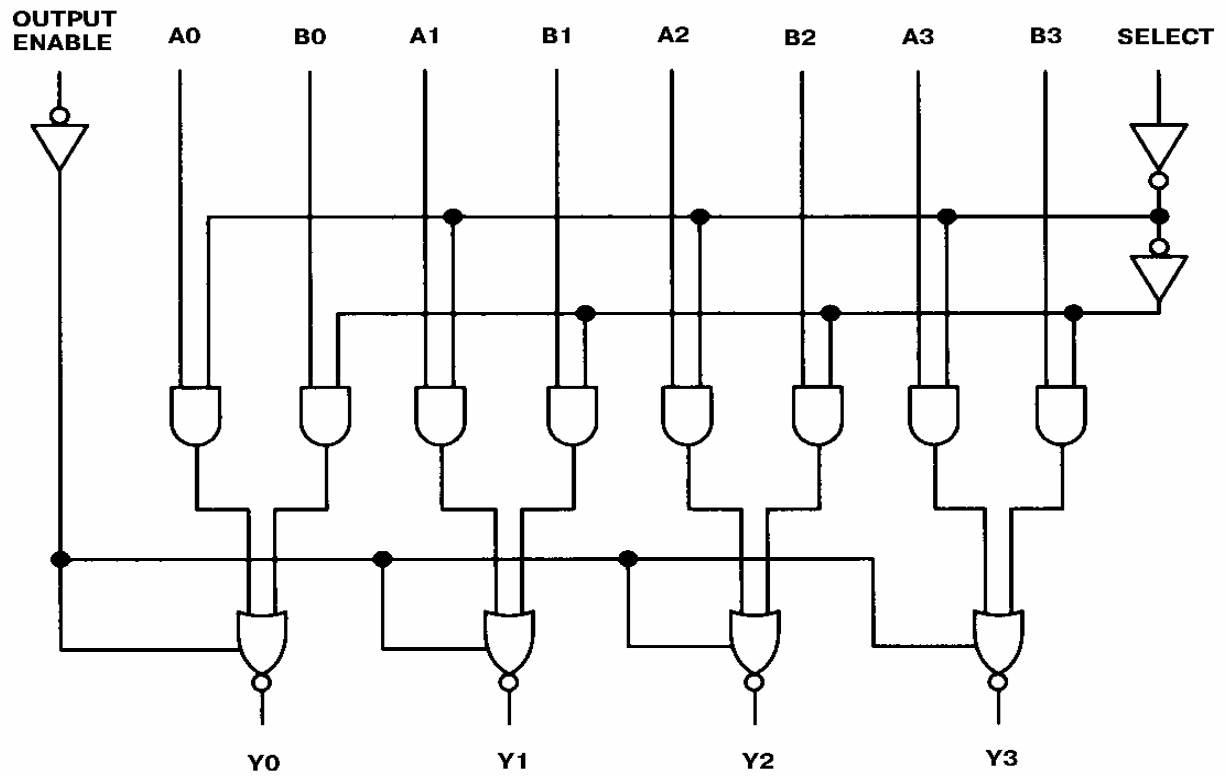
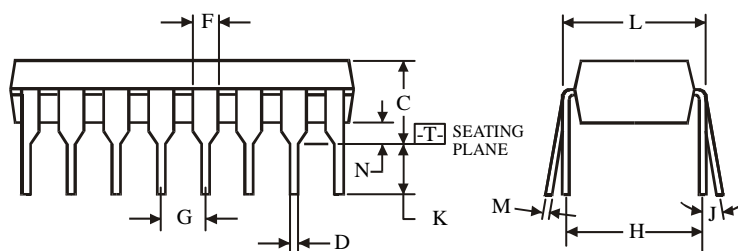
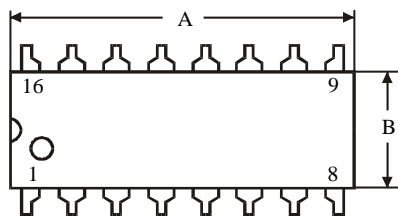
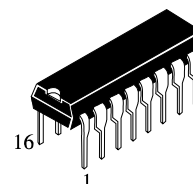


Figure 3. Switching Waveforms

EXPANDED LOGIC DIAGRAM



**N SUFFIX PLASTIC DIP  
(MS - 001BB)**



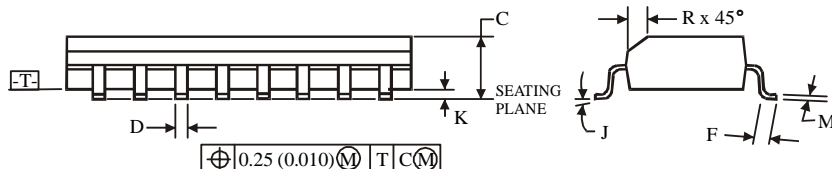
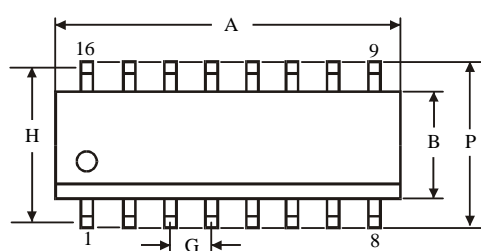
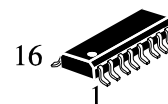
$\oplus 0.25 (0.010) \text{ (M) T}$

**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions.  
Maximum mold flash or protrusions 0.25 mm (0.010) per side.

Symbol	Dimension, mm	
	MIN	MAX
A	18.67	19.69
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**D SUFFIX SOIC  
(MS - 012AC)**



$\oplus 0.25 (0.010) \text{ (M) T C (M)}$

**NOTES:**

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side  
for A; for B - 0.25 mm (0.010) per side.

Symbol	Dimension, mm	
	MIN	MAX
A	9.8	10
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5